74LVC1G125

SINGLE BUFFER GATE WITH 3-STATE OUTPUT

NEW PRODUCT

Description

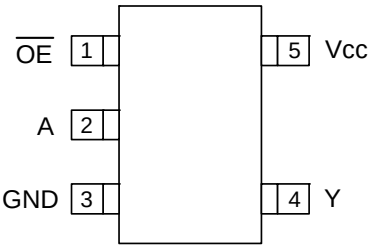
The 74LVC1G125 is a single non-inverting buffer/bus driver with a 3-state output. The output enters a high impedance state when a HIGH-level is applied to the output enable ($\overline{OE}$) pin. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

Features

- Wide Supply Voltage Range from 1.65 to 5.5V
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- I_{OFF} Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
  - Exceeds 200-V Machine Model (A115-A)
  - Exceeds 2000-V Human Body Model (A114-A)
- Latch-Up Exceeds 100mA per JESD 78, Class II Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- Direct Interface with TTL Levels
- SOT25, SOT353, and DFN1410: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

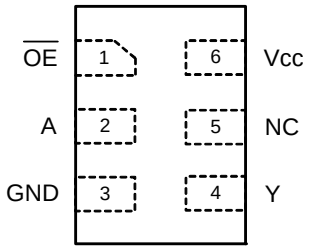
Pin Assignments

(Top View)



SOT25 / SOT353

(Top View)



DFN1410 (Note 2)

Applications

- Voltage Level Shifting
- Bus Driver / Repeater
- Power Down Signal Isolation
- General Purpose Logic
- Wide array of products such as.
  - PCs, networking, notebooks, netbooks, PDAs
  - Computer peripherals, hard drives, CD/DVD ROM
  - TV, DVD, DVR, set top box
  - Cell Phones, Personal Navigation / GPS
  - MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.

2. Pin 2 and pin 5 of the DFN1410 package are internally connected.

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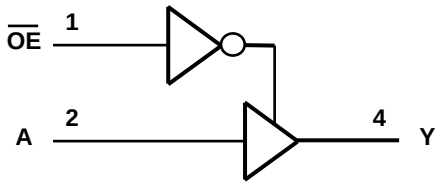
Pin Descriptions

Pin Name	Description
$\overline{OE}$	Output Enable
A	Data Input
GND	Ground
Y	Data Output
Vcc	Supply Voltage
NC	No Connection

Logic Diagram



Function Table

Inputs		Output
$\overline{OE}$	A	Y
L	H	H
L	L	L
H	X	Z

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Absolute Maximum Ratings (Note 3)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to 6.5	V
V_I	Input Voltage Range	-0.5 to 6.5	V
V_o	Voltage applied to output in high impedance or I_{OFF} state	-0.5 to 6.5	V
V_o	Voltage applied to output in high or low state	-0.3 to V_{CC} +0.5	V
I_{IK}	Input Clamp Current V_I<0	-50	mA
I_{OK}	Output Clamp Current	-50	mA
I_O	Continuous output current	±50	mA
	Continuous current through Vdd or GND	±100	mA
T_J	Operating Junction Temperature	-40 to 150	°C
T_{STG}	Storage Temperature	-65 to 150	°C

Notes: 3. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

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Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Unit
V_{CC}	Operating Voltage	Operating	1.65	5.5	V
		Data retention only	1.5		V
V_{IH}	High-level Input Voltage	V_{CC} = 1.65V to 1.95V	0.65 X V_{CC}		V
		V_{CC} = 2.3V to 2.7V	1.7		
		V_{CC} = 3V to 3.6V	2		
		V_{CC} = 4.5V to 5.5V	0.7 X V_{CC}		
V_{IL}	Low-level input voltage	V_{CC} = 1.65V to 1.95V		0.35 X V_{CC}	V
		V_{CC} = 2.3V to 2.7V		0.7	
		V_{CC} = 3V to 3.6V		0.8	
		V_{CC} = 4.5V to 5.5V		0.3 X V_{CC}	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage		0	V_{CC}	V
I_{OH}	High-level output current	V_{CC} = 1.65V		-4	mA
		V_{CC} = 2.3V		-8	
		V_{CC} = 3V		-16	
				-24	
		V_{CC} = 4.5V		-32	
I_{OL}	Low-level output current	V_{CC} = 1.65V		4	mA
		V_{CC} = 2.3V		8	
		V_{CC} = 3V		16	
				24	
		V_{CC} = 4.5V		32	
$\Delta t/\Delta V$	Input transition rise or fall rate	V_{CC} = 1.8V ± 0.15V, 2.5V ± 0.2V		20	ns/V
		V_{CC} = 3.3V ± 0.3V		10	
		V_{CC} = 5V ± 0.5V		5	
T_A	Operating free-air temperature		-40	85	ºC

Notes: 4. Unused inputs should be held at Vcc or Ground.

NEW PRODUCT

Electrical Characteristics (All typical values are at Vcc = 3.3V, T_A = 25°C)

Over recommended free-air temperature range (unless otherwise noted)

Symbol	Parameter	Test Conditions	Vcc	Min	Typ.	Max	Unit
V_{OH}	High Level Output Voltage	I_{OH} = -100µA	1.65V to 5.5V	V_{CC} – 0.1			V
		I_{OH} = -4mA	1.65V	1.2			
		I_{OH} = -8mA	2.3V	1.9			
		I_{OH} = -16mA	3V	2.4			
		I_{OH} = -24mA		2.3			
		I_{OH} = -32mA	4.5V	3.8			
V_{OL}	High-level Input Voltage	I_{OL} = 100µA	1.65V to 5.5V			0.1	V
		I_{OL} = 4mA	1.65V			0.45	
		I_{OL} = 8mA	2.3V			0.3	
		I_{OL} = 16mA	3V			0.4	
		I_{OL} = 24mA				0.55	
		I_{OL} = 32mA	4.5V			0.55	
I_I	Input Current	V_I = 5.5V or GND	0 to 5.5V			± 5	µA
I_{OFF}	Power Down Leakage Current	V_I or V_O = 5.5V	0			± 10	µA
I_{OZ}	Z State Leakage Current	V_O =0 to 5.5V	3.6V			± 10	µA
I_{CC}	Supply Current	V_I = 5.5V of GND I_O=0	1.65V to 5.5V			10	µA
ΔI_{CC}	Additional Supply Current	One input at V_{CC} – 0.6 V Other inputs at V_{CC} or GND	3V to 5.5V			500	µA
C_i	Input Capacitance	V_i = V_{CC} – or GND	3.3		4		pF
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOT25	(Note 5)		204		°C/W
		SOT353	(Note 5)		371		°C/W
		DFN1410	(Note 5)		430		°C/W
θ_{JC}	Thermal Resistance Junction-to-Case	SOT25	(Note 5)		52		°C/W
		SOT353	(Note 5)		143		°C/W
		DFN1410	(Note 5)		190		°C/W

Notes: 5. Test condition for SOT25, SOT353, and DFN1410: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

NEW PRODUCT

Switching Characteristics

Over recommended free-air temperature range, CL = 15pF (see Figure 1)

Parameter	From (Input)	TO (OUTPUT)	Vcc = 1.8 V ± 0.15V		Vcc = 2.5 V ± 0.2V		Vcc = 3.3 V ± 0.3V		Vcc = 5 V ± 0.5V		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	
t_{pd}	A	Y	1.9	6.9	0.7	4.6	0.6	3.7	0.5	3.4	ns

Over recommended free-air temperature range, CL = 30 or 50pF as noted (see Figure 2)

Parameter	From (Input)	TO (OUTPUT)	Vcc = 1.8 V ± 0.15V		Vcc = 2.5 V ± 0.2V		Vcc = 3.3 V ± 0.3V		Vcc = 5 V ± 0.5V		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	
t_{pd}	A	Y	2.8	9.0	1.2	5.5	1.0	4.5	1.0	4.0	ns
t_{en}	$\overline{OE}$	Y	2.8	10.1	1.5	6.6	1.0	5.3	1.0	5.0	ns
t_{dis}	$\overline{OE}$	Y	1.3	9.2	1.0	5.5	1.0	5.5	1.0	4.2	ns

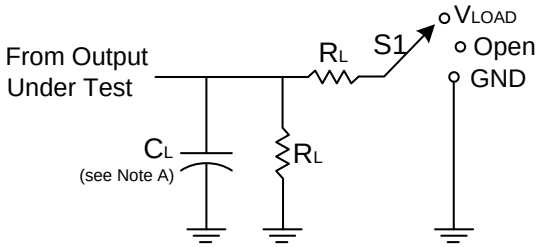
Operating Characteristics

T_A = 25 ºC

Parameter			Test Conditions	Vcc = 1.8 V	Vcc = 2.5 V	Vcc = 3.3 V	Vcc = 5 V	Unit
				TYP	TYP	TYP	TYP	
C_{pd}	Power dissipation capacitance	Outputs enabled	f = 10 MHz	19	19	19	21	pF
		Outputs disabled		2	2	3	4	

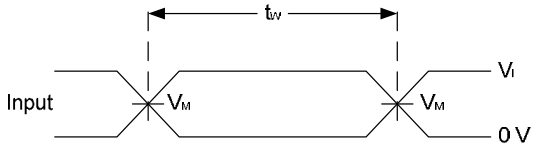
NEW PRODUCT

Parameter Measurement Information

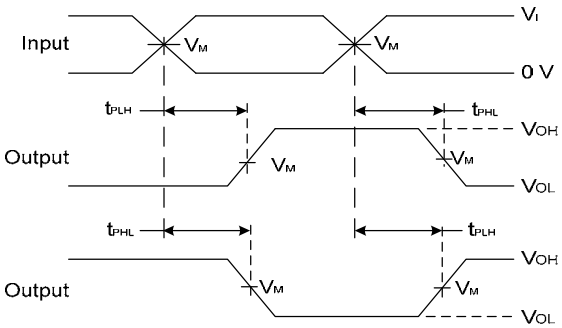


TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	Vload
t_{PHZ}/t_{PZH}	GND

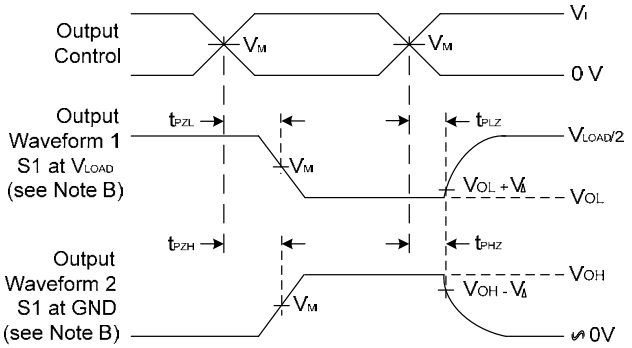
Vcc	Inputs		V_M	V_{LOAD}	C_L	R_L	$V\Delta$
	V_I	t_r/t_f					
1.8V±0.15V	V_{CC}	≤2ns	$V_{CC}/2$	2 X V_{CC}	15pF	1MΩ	0.15V
2.5V±0.2V	V_{CC}	≤2ns	$V_{CC}/2$	2 X V_{CC}	15pF	1MΩ	0.15V
3.3V±0.3V	3V	≤2.5ns	1.5V	6V	15pF	1MΩ	0.3V
5V±0.5V	V_{CC}	≤2.5ns	$V_{CC}/2$	2 X V_{CC}	15pF	1MΩ	0.3V



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



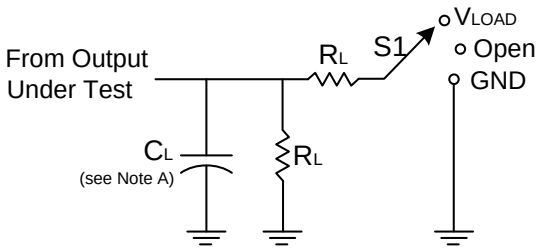
Voltage Waveform Enable and Disable Times Low and High Level Enabling

Figure 1. Load Circuit and Voltage Waveforms

Notes:
A. Includes test lead and test apparatus capacitance.
B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
C. Inputs are measured separately one transition per measurement.
D. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
E. t_{PZL} and t_{PZH} are the same as t_{EN}.
F. t_{PLH} and t_{PHL} are the same as t_{PD}.

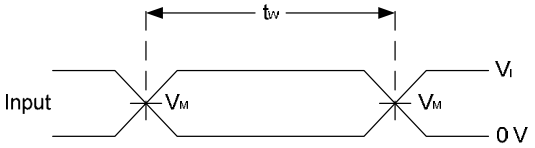
NEW PRODUCT

Parameter Measurement Information (Continued)

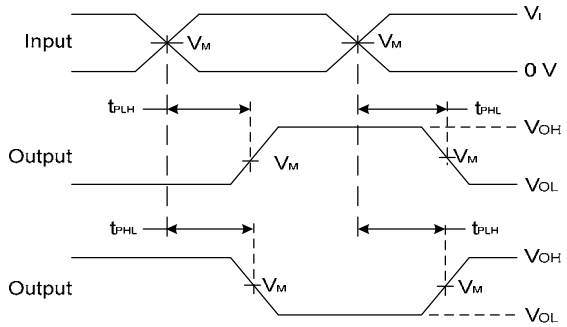


TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	Vload
t_{PHZ}/t_{PZH}	GND

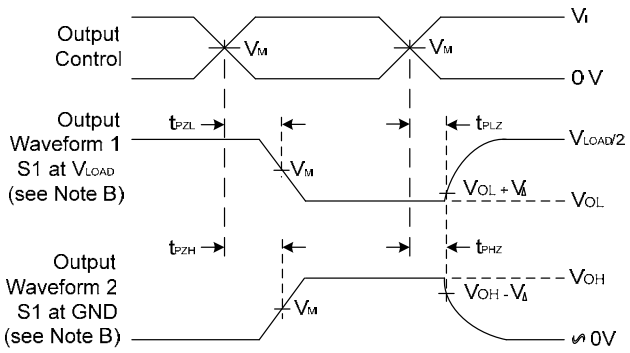
Vcc	Inputs		V_M	V_{LOAD}	C_L	R_L	$V\Delta$
	V_I	t_r/t_f					
1.8V±0.15V	V_{CC}	≤2ns	$V_{CC}/2$	2 X V_{CC}	30pF	1KΩ	0.15V
2.5V±0.2V	V_{CC}	≤2ns	$V_{CC}/2$	2 X V_{CC}	30pF	500Ω	0.15V
3.3V±0.3V	3V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V
5V±0.5V	V_{CC}	≤2.5ns	$V_{CC}/2$	2 X V_{CC}	50pF	500Ω	0.3V



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



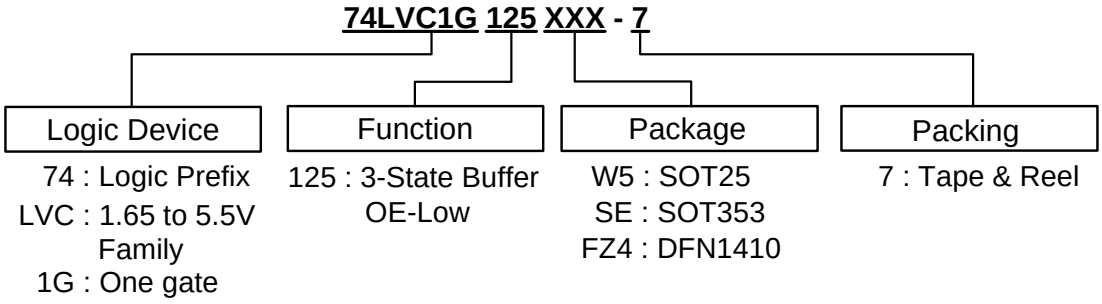
Voltage Waveform Enable and Disable Times Low and High Level Enabling

Figure 2. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.
B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
C. Inputs are measured separately one transition per measurement.
D. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
E. t_{PZL} and t_{PZH} are the same as t_{EN0}
F. t_{PLH} and t_{PHL} are the same as t_{PD}.

NEW PRODUCT

Ordering Information



Device	Package Code	Packaging (Note 6)	7" Tape and Reel	
			Quantity	Part Number Suffix
74LVC1G125W5-7	W5	SOT25	3000/Tape & Reel	-7
74LVC1G125SE-7	SE	SOT353	3000/Tape & Reel	-7
74LVC1G125FZ4-7	FZ4	DFN1410	5000/Tape & Reel	-7

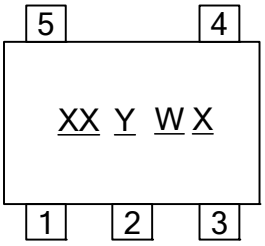
Notes: 6. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

NEW PRODUCT

Marking Information

(1) SOT25 and SOT353

(Top View)

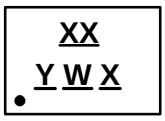


XX : Identification code
Y : Year 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week; z represents
52 and 53 week
X : A~Z : Internal code

Part Number	Package	Identification Code
74LVC1G125W5	SOT25	UY
74LVC1G125SE	SOT353	UY

(2) DFN1410

(Top View)



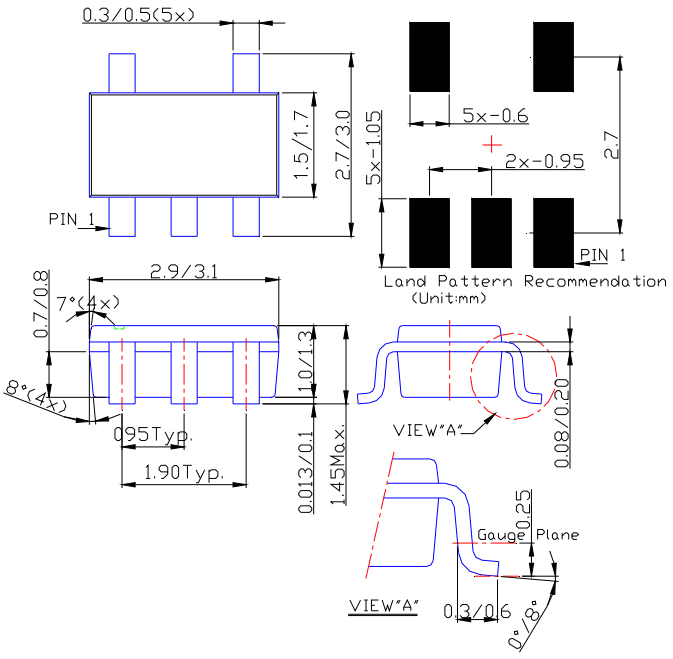
XX : Identification Code
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week; z represents
52 and 53 week
X : A~Z : Internal code

Part Number	Package	Identification Code
74LVC1G125FZ4	DFN1410	UY

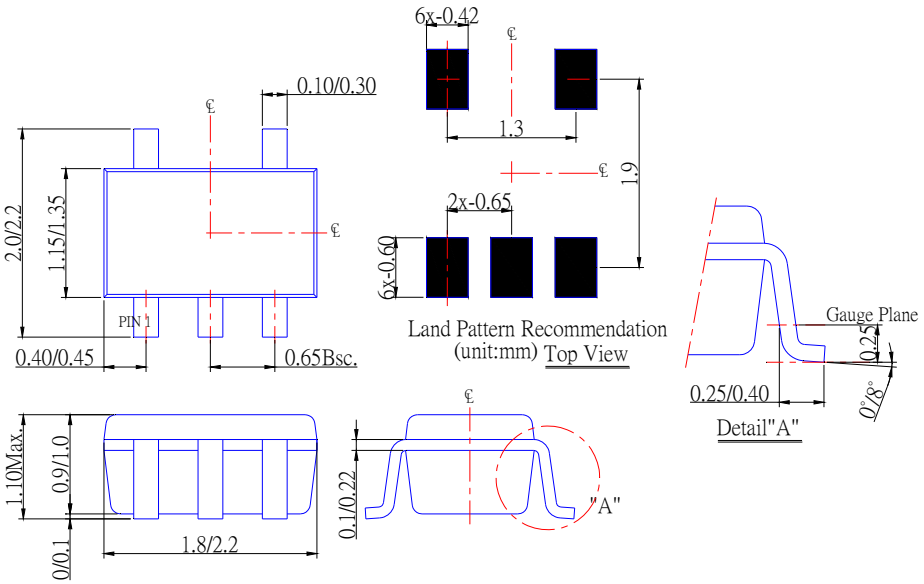
NEW PRODUCT

Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



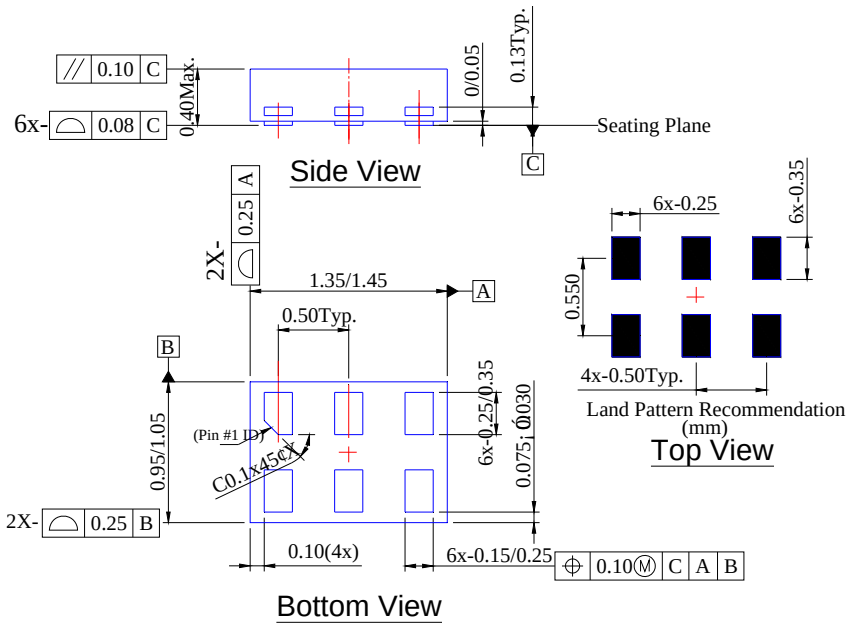
(2) Package Type: SOT353



NEW PRODUCT

Package Outline Dimensions (Continued)

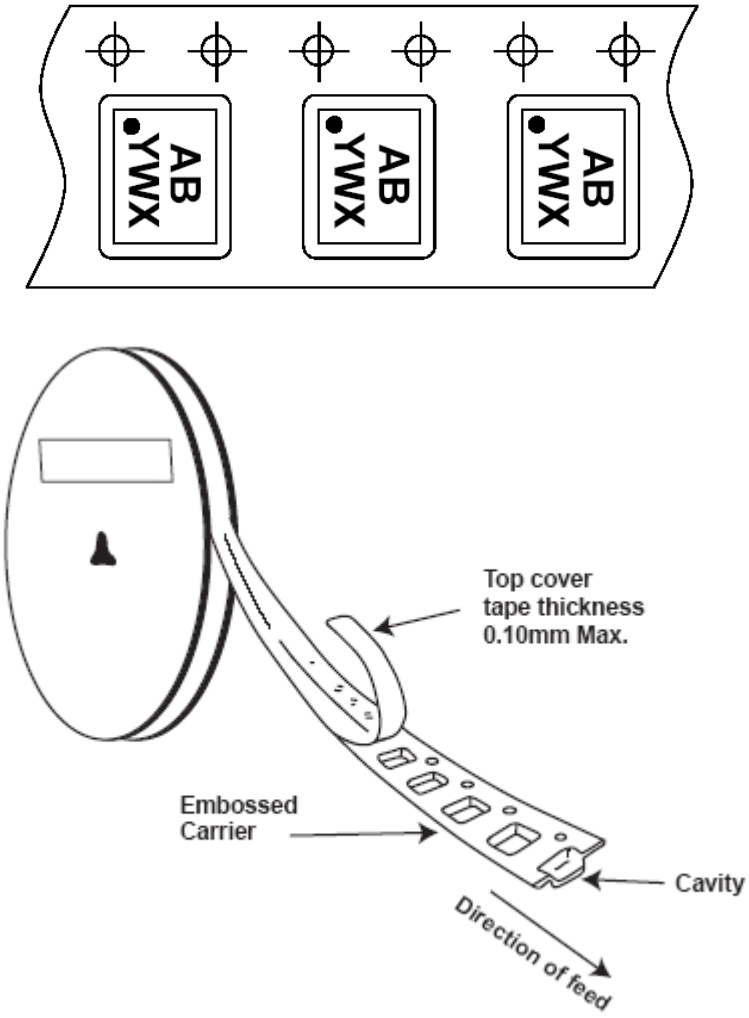
(3) Package Type: DFN1410



NEW PRODUCT

Taping Orientation (Note 7)

For DFN1410



Notes: 7. The taping orientation of the other package type can be found on our website at http://www.diodes.com/datasheets/ap02007.pdf

NEW PRODUCT

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